

Micropower Voltage Reference Diodes

The HT285/HT385 series are micropower two-terminal bandgap voltage regulator diodes. Designed to operate over a wide current range of 10 μ A to 20 mA, these devices feature exceptionally low dynamic impedance, low noise and stable operation over time and temperature. Tight voltage tolerances are achieved by on-chip trimming. The large dynamic operating range enables these devices to be used in applications with widely varying supplies with excellent regulation. Extremely low operating current make these devices ideal for micropower circuitry like portable instrumentation, regulators and other analog circuitry where extended battery life is required.

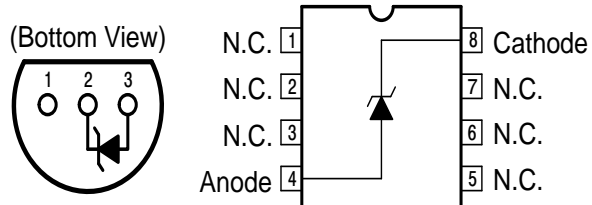
The HT285/HT385 series are packaged in a low cost TO-226 plastic case and are available in two voltage versions of 1.235 V and 2.500 V as denoted by the device suffix (see Ordering Information table). The HT285 is specified over a -40°C to $+85^{\circ}\text{C}$ temperature range while the HT385 is rated from 0°C to $+70^{\circ}\text{C}$.






The HT385 is also available in a surface mount plastic package in voltages of 1.235 V and 2.500 V.

Features

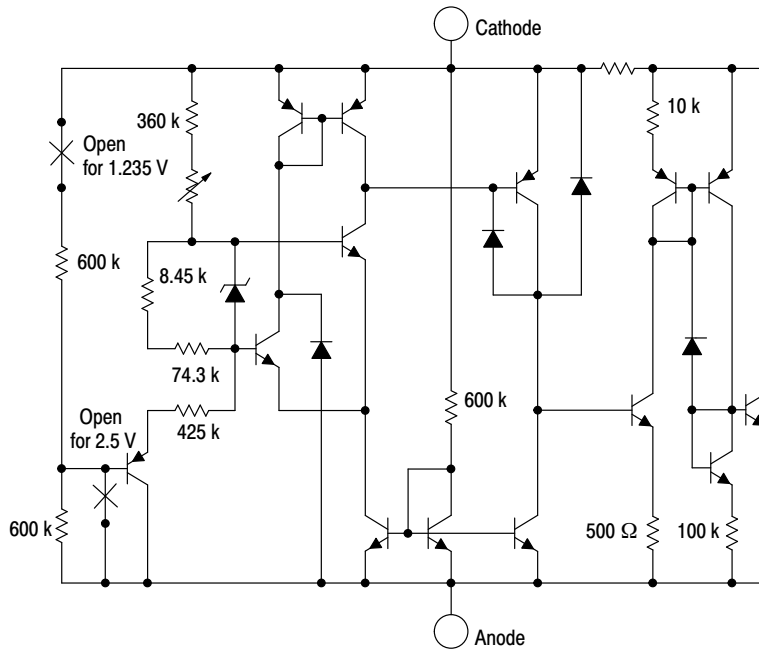
- Operating Current from 10 μ A to 20 mA
- 1.0%, 1.5%, 2.0% and 3.0% Initial Tolerance Grades
- Low Temperature Coefficient
- 1.0 Ω Dynamic Impedance
- Surface Mount Package Available
- These Devices are Pb-Free and are RoHS Compliant

PIN CONNECTIONS

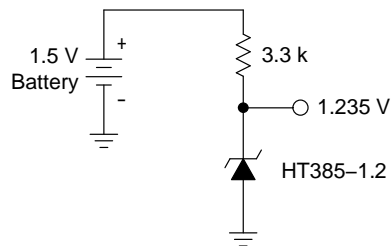


	SOP89-3 D SUFFIX HT385D-xx HT285D-xx
	MSOP-8 M SUFFIX HT385M-xx HT285M-xx
	SOP-8 R SUFFIX HT385R-xx HT285R-xx
	TO92 M SUFFIX HT385T-xx HT285T-xx
	TO-92-3L T SUFFIX HT385AT-xx HT285AT-xx

Representative Schematic Diagram



Standard Application



MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

Rating	Symbol	Value	Unit
Reverse Current	I_R	30	mA
Forward Current	I_F	10	mA
Operating Ambient Temperature Range	T_A	-40 to +85 0 to +70	$^\circ\text{C}$
	HT285 HT385		
Operating Junction Temperature	T_J	+150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-65 to +150	$^\circ\text{C}$
Electrostatic Discharge Sensitivity (ESD)	ESD		V
Human Body Model (HBM)		4000	
Machine Model (MM)		400	
Charged Device Model (CDM)		2000	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

Characteristic	Symbol	HT285-1.2			HT385-1.2/HT385R-1.2			Unit
		Min	Typ	Max	Min	Typ	Max	
Reverse Breakdown Voltage ($I_{R\text{min}} \leq I_R \leq 20 \text{ mA}$) HT285-1.2/HT385R-1.2 $T_A = T_{\text{low}}$ to T_{high} (Note 1) HT385-1.2 $T_A = T_{\text{low}}$ to T_{high} (Note 1)	$V_{(\text{BR})R}$	1.223 1.200	1.235 -	1.247 1.270	1.223 1.210	1.235 -	1.247 1.260	V
Minimum Operating Current $T_A = 25^\circ\text{C}$ $T_A = T_{\text{low}}$ to T_{high} (Note 1)	$I_{R\text{min}}$	- -	8.0 -	10 20	- -	8.0 -	15 20	μA
Reverse Breakdown Voltage Change with Current $I_{R\text{min}} \leq I_R \leq 1.0 \text{ mA}$, $T_A = +25^\circ\text{C}$ $T_A = T_{\text{low}}$ to T_{high} (Note 1) $1.0 \text{ mA} \leq I_R \leq 20 \text{ mA}$, $T_A = +25^\circ\text{C}$ $T_A = T_{\text{low}}$ to T_{high} (Note 1)	$\Delta V_{(\text{BR})R}$	- -	- -	1.0 1.5 10 20	- -	- -	1.0 1.5 20 25	mV
Reverse Dynamic Impedance $I_R = 100 \mu\text{A}$, $T_A = +25^\circ\text{C}$	Z	-	0.6	-	-	0.6	-	Ω
Average Temperature Coefficient $10 \mu\text{A} \leq I_R \leq 20 \text{ mA}$, $T_A = T_{\text{low}}$ to T_{high} (Note 1)	$\Delta V_{(\text{BR})}/\Delta T$	-	80	-	-	80	-	ppm/ $^\circ\text{C}$
Wideband Noise (RMS) $I_R = 100 \mu\text{A}$, $10 \text{ Hz} \leq f \leq 10 \text{ kHz}$	n	-	60	-	-	60	-	μV
Long Term Stability $I_R = 100 \mu\text{A}$, $T_A = +25^\circ\text{C} \pm 0.1^\circ\text{C}$	S	-	20	-	-	20	-	ppm/kHR
Reverse Breakdown Voltage ($I_{R\text{min}} \leq I_R \leq 20 \text{ mA}$) HT285-2.5/HT385R-2.5 $T_A = T_{\text{low}}$ to T_{high} (Note 1) HT385-2.5 $T_A = T_{\text{low}}$ to T_{high} (Note 1)	$V_{(\text{BR})R}$	2.462 2.415	2.5 -	2.538 2.585	2.462 2.436	2.5 -	2.538 2.564 2.575 2.600	V
Minimum Operating Current $T_A = 25^\circ\text{C}$ $T_A = T_{\text{low}}$ to T_{high} (Note 1)	$I_{R\text{min}}$	- -	13 -	20 30	- -	13 -	20 30	μA

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

Characteristic	Symbol	HT285-1.2			HT385-1.2/HT385R-1.2			Unit
		Min	Typ	Max	Min	Typ	Max	
Reverse Breakdown Voltage Change with Current $I_{Rmin} \leq I_R \leq 1.0 \text{ mA}$, $T_A = +25^\circ\text{C}$ $T_A = T_{low}$ to T_{high} (Note 2) $1.0 \text{ mA} \leq I_R \leq 20 \text{ mA}$, $T_A = +25^\circ\text{C}$ $T_A = T_{low}$ to T_{high} (Note 2)	$\Delta V_{(BR)R}$	-	-	1.0	-	-	2.0	mV
		-	-	1.5	-	-	2.5	
		-	-	10	-	-	20	
		-	-	20	-	-	25	
Reverse Dynamic Impedance $I_R = 100 \mu\text{A}$, $T_A = +25^\circ\text{C}$	Z	-	0.6	-	-	0.6	-	Ω
Average Temperature Coefficient $20 \mu\text{A} \leq I_R \leq 20 \text{ mA}$, $T_A = T_{low}$ to T_{high} (Note 2)	$\Delta V_{(BR)}/\Delta T$	-	80	-	-	80	-	ppm/ $^\circ\text{C}$
Wideband Noise (RMS) $I_R = 100 \mu\text{A}$, $10 \text{ Hz} \leq f \leq 10 \text{ kHz}$	n	-	120	-	-	120	-	μV
Long Term Stability $I_R = 100 \mu\text{A}$, $T_A = +25^\circ\text{C} \pm 0.1^\circ\text{C}$	S	-	20	-	-	20	-	ppm/kHR

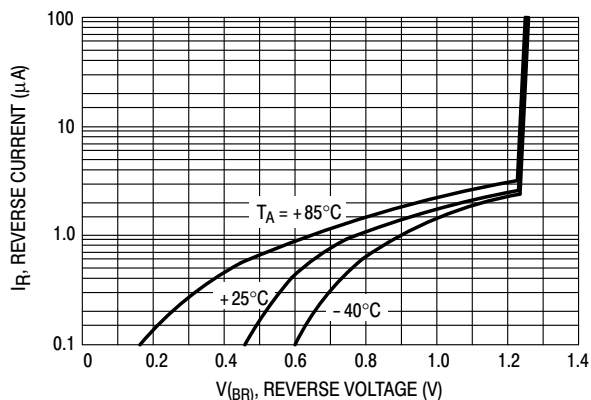


Figure 2. Reverse Characteristics

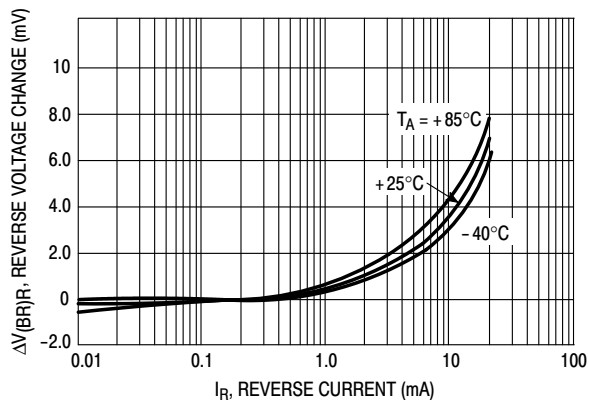


Figure 3. Reverse Characteristics

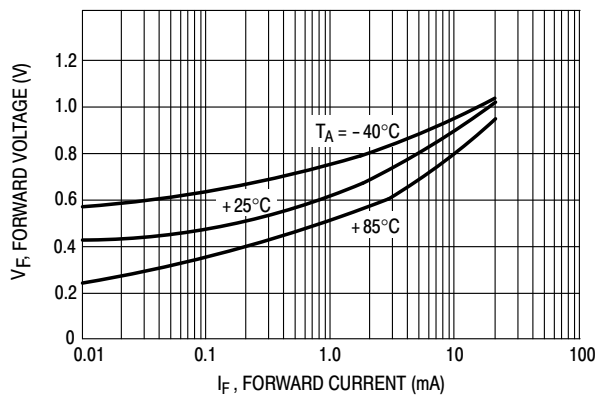


Figure 4. Forward Characteristics

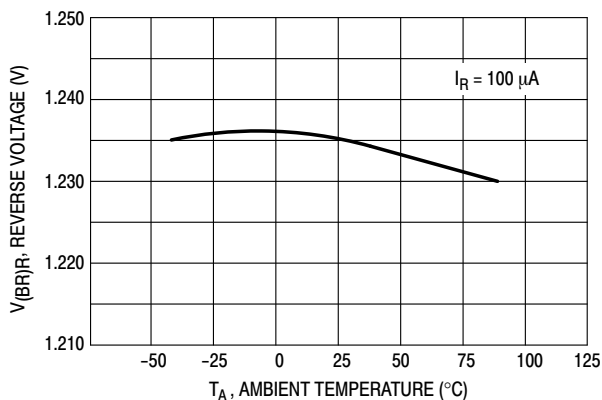


Figure 5. Temperature Drift

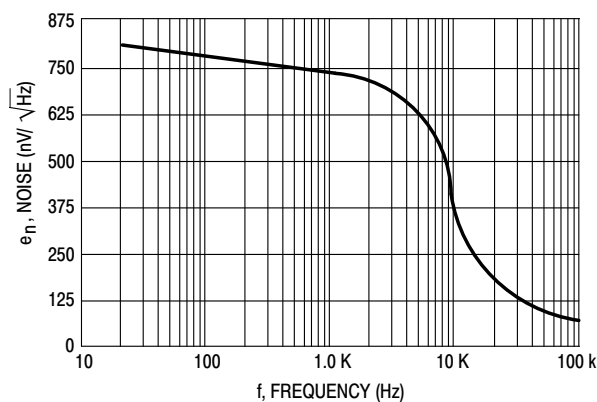


Figure 6. Noise Voltage

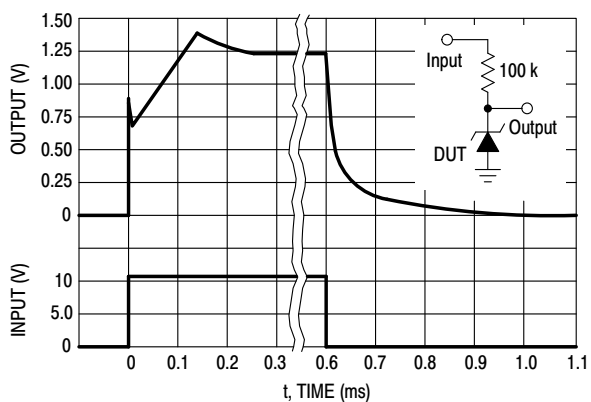


Figure 7. Response Time

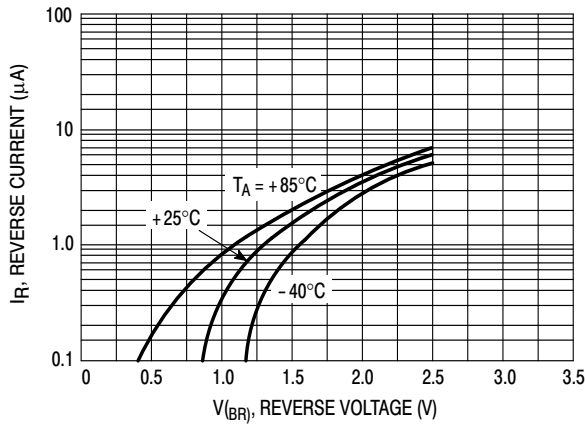


Figure 8. Reverse Characteristics

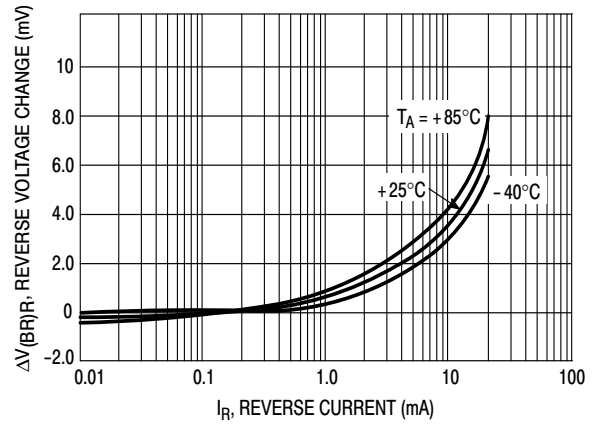


Figure 9. Reverse Characteristics

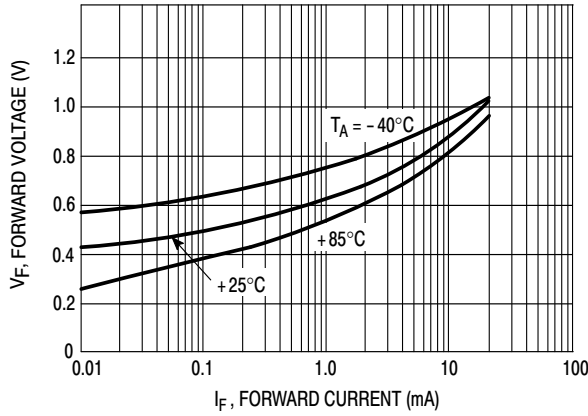


Figure 10. Forward Characteristics

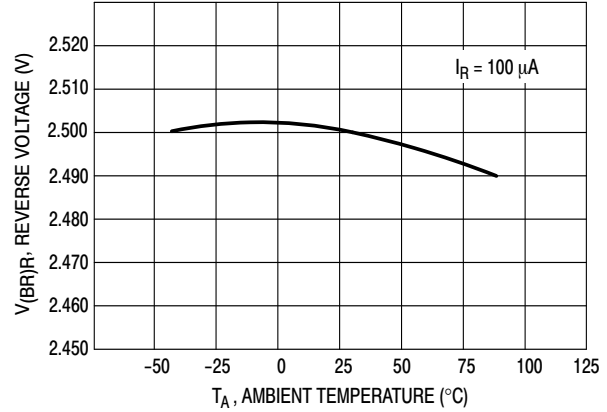


Figure 11. Temperature Drift

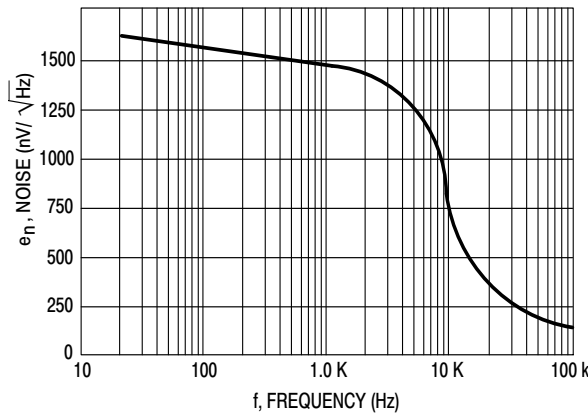


Figure 12. Noise Voltage

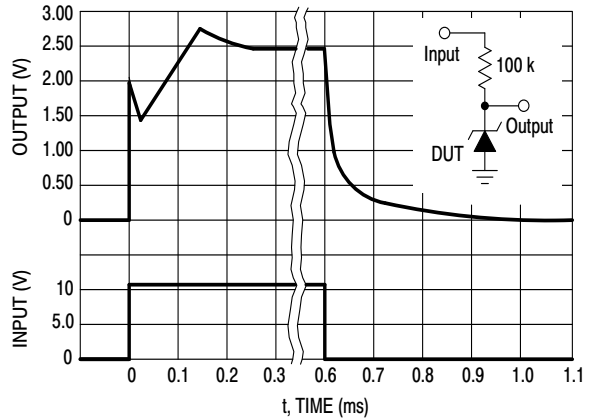
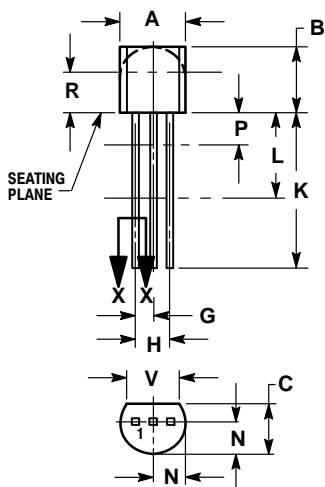
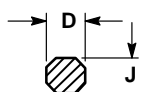
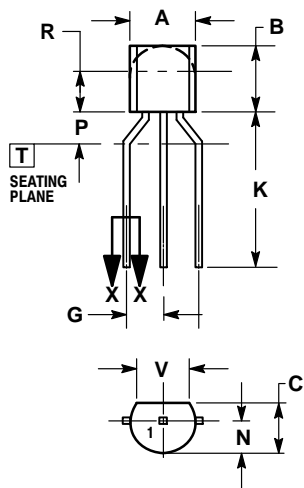
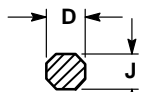


Figure 13. Response Time

PACKAGE DIMENSIONS
**TO-92 (TO-226)
 CASE 29-11
 ISSUE AM**

**STRAIGHT LEAD
 BULK PACK**

SECTION X-X
NOTES:

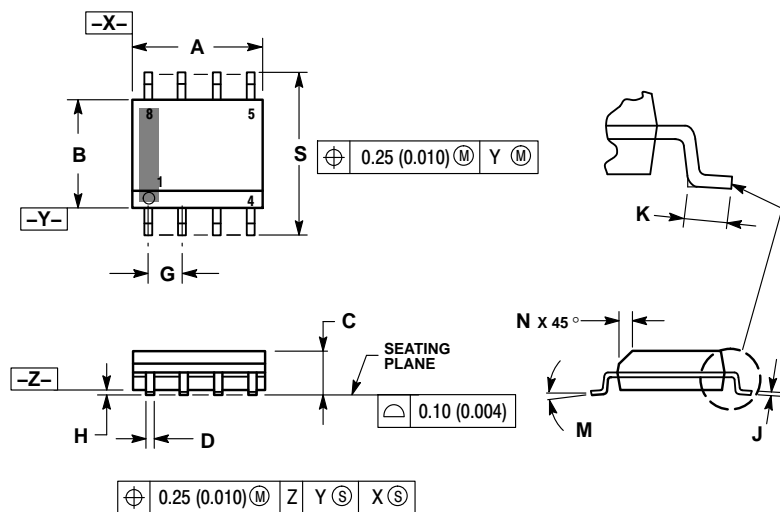
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---


**BENT LEAD
 TAPE & REEL
 AMMO PACK**

SECTION X-X
NOTES:

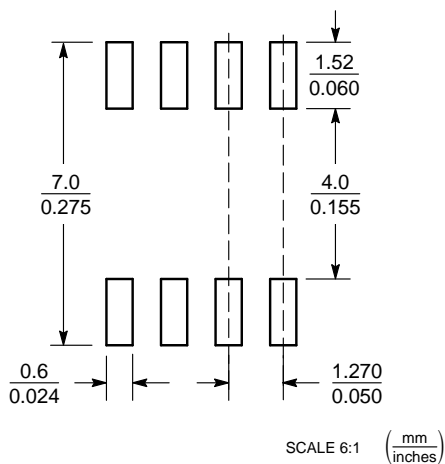
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	MILLIMETERS	
	MIN	MAX
A	4.45	5.20
B	4.32	5.33
C	3.18	4.19
D	0.40	0.54
G	2.40	2.80
J	0.39	0.50
K	12.70	---
N	2.04	2.66
P	1.50	4.00
R	2.93	---
V	3.43	---

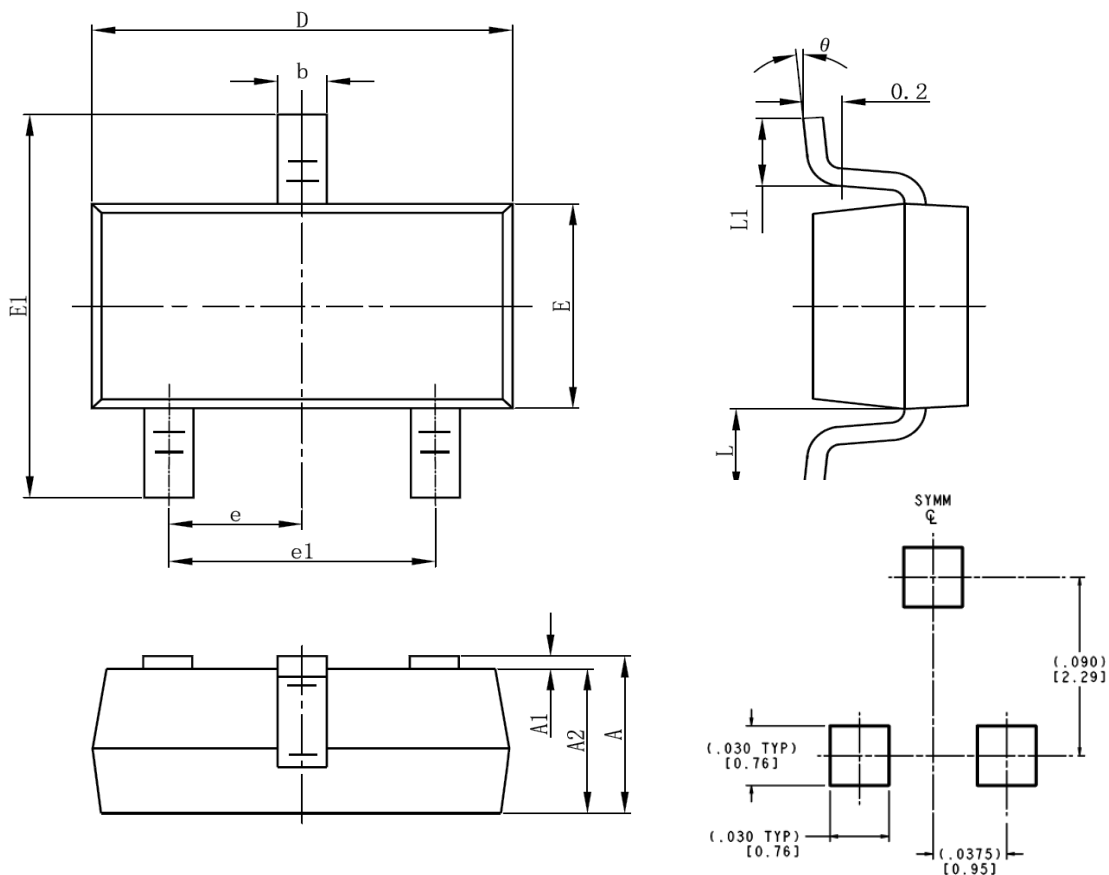
PACKAGE DIMENSIONS
SOIC-8 NB
 CASE 751-07
 ISSUE AK

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0°	8°	0°	8°
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

SOLDERING FOOTPRINT*


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

SOT-23-3L PACKAGE OUTLINE DIMENSIONS


LAND PATTERN RECOMMENDATION

Symbol	Dimensions In Millimeters		Dimensions in inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.400	0.012	0.016
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.700REF		0.028REF	
L1	0.300	0.600	0.012	0.024
theta	0°	8°	0°	8°

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[NJM2823F-TE1](#) [EL5226IR](#) [EL5326IR](#) [EL5326IRZ](#) [ISL21007DFB825Z](#) [ISL21009BFB812Z](#) [ISL21009CFB812Z](#) [ISL60002BIH312](#)
[TS3320AMR](#) [TS3325AMR](#) [TS3330AMR](#) [TS3333AMR](#) [X60003CIG3-41](#) [X60003DIG3Z-41T1](#) [X60250V8I](#) [REF3025TB-GT3](#)
[SC432BVSNT1G](#) [TL431CPG](#) [ADR4520ARZ-R7](#) [ADR4533BRZ-R7](#) [LT1027CCS8-5#TRPBF](#) [REF35102QDBVR](#) [AD587KRZ-REEL](#)
[ADR425ARZ-REEL7](#) [CA-HP6025S](#) [CA-HP6041S](#) [JTL431A](#) [TLVH431NAQDBZRR](#) [REF2033QDDCRQ1](#) [REF35330QDBVR](#)
[ADR4530BRZ-R7](#) [LT1236BCS8-5#TRPBF](#) [ADR435BRMZ-REEL7](#) [CA-HP6050S](#) [TL431](#) [BR431RM](#) [MSR025](#) [MC1403BN](#) [LM285Z-2.5](#)
[LM385B-ADJ](#) [LM385B-2.5](#) [HT385R-1.2](#) [HT336R-2.5](#)